



40V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
40V	$15m\Omega$ @ $V_{GS} = 10V$	43.6A
	$25m\Omega @ V_{GS} = 4.5V$	33A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

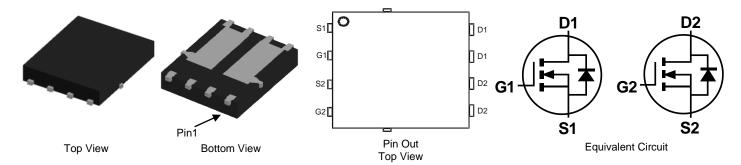
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMTH4014LPDQ</u>)

Mechanical Data

- Case: PowerDI[®] 5060-8 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 [®]
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

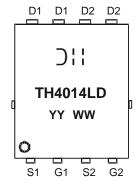
Part Number	Case	Packaging
DMTH4014LPD-13	PowerDI5060-8 (Type C)	2,500/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



);; = Manufacturer's Marking
TH4014LD = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 18 = 2018)
WW = Week (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 5)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	43.6 30.8	А
Continuous Drain Current (Note 6) $ T_A = +25^{\circ}C $ $ T_A = +100^{\circ}C $		I _D	10.6 7.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	75	A	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	36	A	
Avalanche Current, L = 0.3mH	I _{AS}	11.7	А	
Avalanche Energy, L = 0.3mH	E _{AS}	20.5	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	2.41	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	62.6	°C/W
Total Power Dissipation (Note 6)	P _D	42.8	W
Thermal Resistance, Junction to Case (Note 6)	R ₀ JC	3.5	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		40	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage		_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	1.3	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D	_	11.8	15	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Dialit-Source Off-Nesistance	R _{DS(ON)}	_	17.9	25	11122	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	V _{SD}	_	0.9	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)	•			•			
Input Capacitance	C _{iss}	1	733	_	pF		
Output Capacitance	Coss		235	_	pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	24	_	pF	11 - 1101112	
Gate Resistance	Rg	_	1.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.2	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	10.2	_	nC	, 20V I 20A	
Gate-Source Charge	Qgs	_	1.5	_	nC	$V_{DS} = 20V, I_{D} = 20A$	
Gate-Drain Charge	Q _{gd}	_	3.1	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	-	3.5	_	ns		
Turn-On Rise Time	t _R	-	5.7	_	ns	$V_{DD} = 20V, V_{GS} = 10V,$ $R_{G} = 1.6\Omega, I_{D} = 20A$	
Turn-Off Delay Time	t _{D(OFF)}	_	8.7	_	ns		
Turn-Off Fall Time	t _F	_	1.8	_	ns		
Body Diode Reverse Recovery Time	t _{RR}		11.9	_	ns	154 17/19 1004/	
Body Diode Reverse Recovery Charge	Q _{RR}	_	9.28	_	nC	$I_F = 15A$, di/dt = 400A/ μ s	

5. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate.

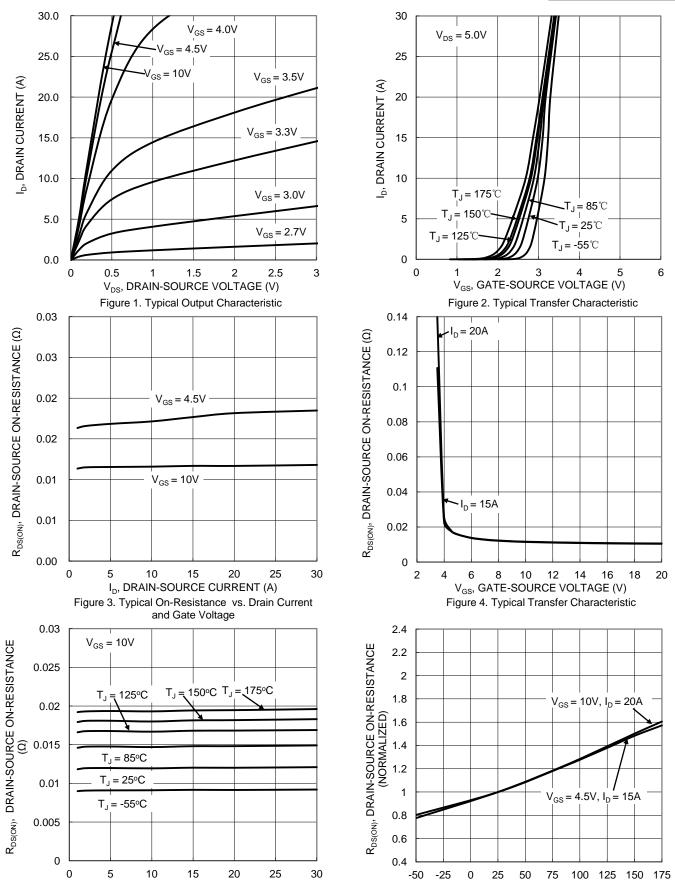
^{6.} Thermal resistance from junction to soldering point (on the exposed drain pad).

^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.







I_D, DRAIN CURRENT (A)

Figure 5. Typical On-Resistance vs. Drain Current and

Temperature

T_J, JUNCTION TEMPERATURE (°C)

Figure 6. On-Resistance Variation with

Temperature





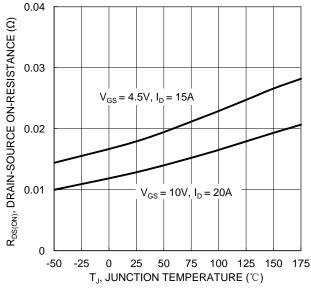


Figure 7. On-Resistance Variation with Temperature

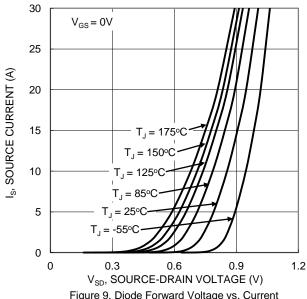


Figure 9. Diode Forward Voltage vs. Current

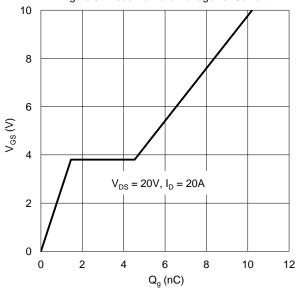


Figure 11. Gate Charge

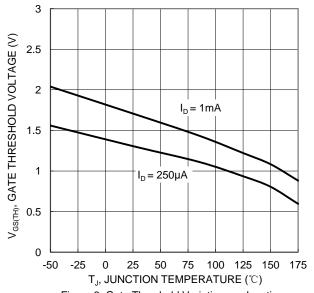
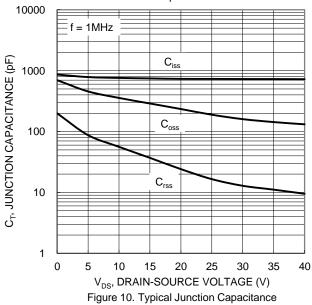


Figure 8. Gate Threshold Variation vs. Junction Temperature



100 Limited 10 ID, DRAIN CURRENT (A) $= 10 \mu$ $P_W = 1 ms$ $P_W = 10 ms$ $T_{J(Max)} = 175^{\circ}C$ $T_C = 25^{\circ}C$ Single Pulse $P_W = 100 ms$ 0.1 $P_W = 1s$ DUT on Infinite Heatsink $V_{GS} = 10V$ 0.01 0.1 1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area

April 2018

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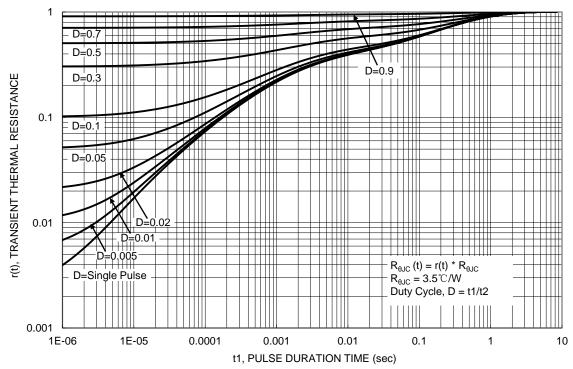


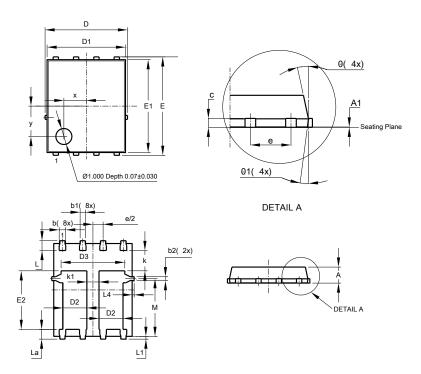
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type C)

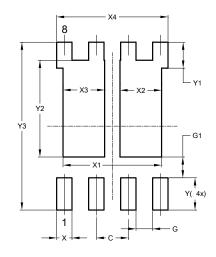


PowerDI5060-8 (Type C)					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
С	0.23	0.33	0.277		
D	,	5.15 BSC	;		
D1	4.85	4.95	4.90		
D2	1.40	1.60	1.50		
D3	-	-	3.98		
Е	6.15 BSC				
E1	5.75	5.85	5.80		
E2	3.56	3.76	3.66		
е	1.27BSC				
k	-	-	1.27		
k1	0.56	-	-		
L	0.51	0.71	0.61		
La	0.51	0.71	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
х	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type C)



Dimensions	Value		
פווטופווסוטווט	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	3.910		
X2	1.650		
Х3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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